

## CRYSTAL OSCILLATOR (XO) 100 kHz TO 250 MHz

### Features

- Supports any frequency from 100 kHz to 250 MHz
- Low jitter operation
- 2 to 4 week lead times
- Total stability includes 10-year aging
- Comprehensive production test coverage includes crystal ESR and DLD
- On-chip LDO regulator for power supply noise filtering
- 3.3, 2.5, or 1.8 V operation
- Differential (LVPECL, LVDS, HCSL) or CMOS output options
- Optional integrated 1:2 CMOS fanout buffer
- Runt suppression on OE and power on
- Industry standard 5 x 7 and 3.2 x 5 mm packages
- Pb-free, RoHS compliant
- -40 to 85 °C operation

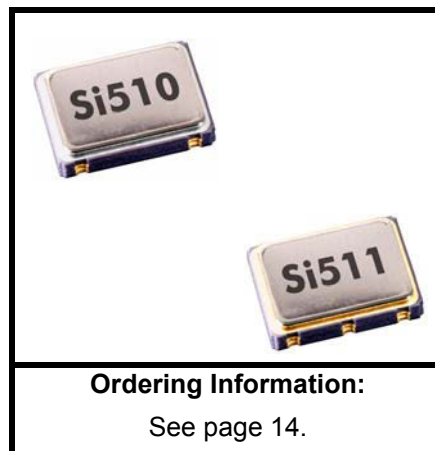
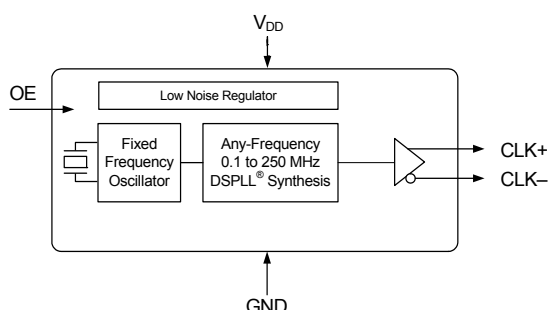
### Applications

- SONET/SDH/OTN
- Gigabit Ethernet
- Fibre Channel/SAS/SATA
- PCI Express
- 3G-SDI/HD-SDI/SDI
- Telecom
- Switches/routers
- FPGA/ASIC clock generation

### Description

The Si510/511 XO utilizes Silicon Laboratories' advanced DSPLL technology to provide any frequency from 100 kHz to 250 MHz. Unlike a traditional XO where a different crystal is required for each output frequency, the Si510/511 uses one fixed crystal and Silicon Labs' proprietary DSPLL synthesizer to generate any frequency across this range. This IC-based approach allows the crystal resonator to provide enhanced reliability, improved mechanical robustness, and excellent stability. In addition, this solution provides superior supply noise rejection, simplifying low jitter clock generation in noisy environments. Crystal ESR and DLD are individually production-tested to guarantee performance and enhance reliability. The Si510/511 is factory-configurable for a wide variety of user specifications, including frequency, supply voltage, output format, output enable polarity, and stability. Specific configurations are factory-programmed at time of shipment, eliminating long lead times and non-recurring engineering charges associated with custom frequency oscillators.

### Functional Block Diagram

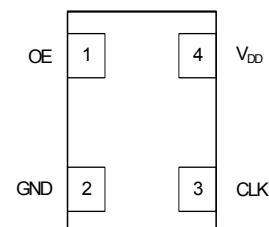


### Ordering Information:

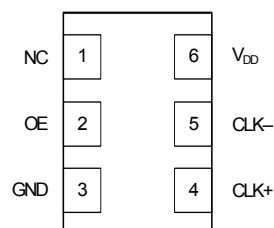
See page 14.

### Pin Assignments:

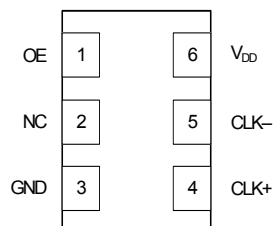
See page 12.



### Si510 (CMOS)



### Si510(LVDS/LVPECL/HCSL/ Dual CMOS)



### Si511(LVDS/LVPECL/HCSL/ Dual CMOS)



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## TABLE OF CONTENTS

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| <b><u>Section</u></b>                                | <b><u>Page</u></b> |
|------------------------------------------------------|--------------------|
| 1. Electrical Specifications .....                   | 4                  |
| 2. Pin Descriptions .....                            | 12                 |
| 2.1. Dual CMOS Buffer .....                          | 13                 |
| 3. Ordering Information .....                        | 14                 |
| 4. Si510/511 Mark Specification .....                | 15                 |
| 5. Package Outline Diagram: 5 x 7 mm, 4-pin .....    | 16                 |
| 6. PCB Land Pattern: 5 x 7 mm, 4-pin .....           | 17                 |
| 7. Package Outline Diagram: 5 x 7 mm, 6-pin .....    | 18                 |
| 8. PCB Land Pattern: 5 x 7 mm, 6-pin .....           | 19                 |
| 9. Package Outline Diagram: 3.2 x 5 mm, 4-pin .....  | 20                 |
| 10. PCB Land Pattern: 3.2 x 5 mm, 4-pin .....        | 21                 |
| 11. Package Outline Diagram: 3.2 x 5 mm, 6-Pin ..... | 22                 |
| 12. PCB Land Pattern: 3.2 x 5.0 mm, 6-pin .....      | 23                 |
| Document Change List .....                           | 24                 |
| Contact Information .....                            | 26                 |

## 1. Electrical Specifications

**Table 1. Operating Specifications**

$V_{DD} = 1.8\text{ V} \pm 5\%$ ,  $2.5\text{ or }3.3\text{ V} \pm 10\%$ ,  $T_A = -40\text{ to }+85\text{ }^{\circ}\text{C}$

| Parameter                               | Symbol   | Test Condition                 | Min                  | Typ | Max                  | Unit               |
|-----------------------------------------|----------|--------------------------------|----------------------|-----|----------------------|--------------------|
| Supply Voltage                          | $V_{DD}$ | 3.3 V option                   | 2.97                 | 3.3 | 3.63                 | V                  |
|                                         |          | 2.5 V option                   | 2.25                 | 2.5 | 2.75                 | V                  |
|                                         |          | 1.8 V option                   | 1.71                 | 1.8 | 1.89                 | V                  |
| Supply Current                          | $I_{DD}$ | CMOS, 100 MHz,<br>single-ended | —                    | 21  | 26                   | mA                 |
|                                         |          | LVDS<br>(output enabled)       | —                    | 19  | 23                   | mA                 |
|                                         |          | LVPECL<br>(output enabled)     | —                    | 39  | 43                   | mA                 |
|                                         |          | HCSL<br>(output enabled)       | —                    | 41  | 44                   | mA                 |
|                                         |          | Tristate<br>(output disabled)  | —                    | —   | 18                   | mA                 |
| OE "1" Setting                          | $V_{IH}$ | See Note                       | $0.80 \times V_{DD}$ | —   | —                    | V                  |
| OE "0" Setting                          | $V_{IL}$ | See Note                       | —                    | —   | $0.20 \times V_{DD}$ | V                  |
| OE Internal Pull-Up/Pull-Down Resistor* | $R_I$    |                                | —                    | 45  | —                    | $k\Omega$          |
| Operating Temperature                   | $T_A$    |                                | -40                  | —   | 85                   | $^{\circ}\text{C}$ |

**\*Note:** Active high and active low polarity OE options available. Active high option includes an internal pull-up. Active low option includes an internal pull-down. See ordering information on page 14.

**Table 2. Output Clock Frequency Characteristics** $V_{DD} = 1.8\text{ V} \pm 5\%$ , 2.5 or 3.3 V  $\pm 10\%$ ,  $T_A = -40$  to  $+85\text{ }^{\circ}\text{C}$ 

| Parameter                                                                                                                                                                                   | Symbol          | Test Condition                                                                        | Min  | Typ | Max   | Unit |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|---------------------------------------------------------------------------------------|------|-----|-------|------|
| Nominal Frequency                                                                                                                                                                           | F <sub>O</sub>  | CMOS, Dual CMOS                                                                       | 0.1  | —   | 212.5 | MHz  |
|                                                                                                                                                                                             | F <sub>O</sub>  | LVDS/LVPECL/HCSL                                                                      | 0.1  | —   | 250   | MHz  |
| Total Stability*                                                                                                                                                                            |                 | Frequency Stability Grade C                                                           | −30  | —   | +30   | ppm  |
|                                                                                                                                                                                             |                 | Frequency Stability Grade B                                                           | −50  | —   | +50   | ppm  |
|                                                                                                                                                                                             |                 | Frequency Stability Grade A                                                           | −100 | —   | +100  | ppm  |
| Temperature Stability                                                                                                                                                                       |                 | Frequency Stability Grade C                                                           | −20  | —   | +20   | ppm  |
|                                                                                                                                                                                             |                 | Frequency Stability Grade B                                                           | −25  | —   | +25   | ppm  |
|                                                                                                                                                                                             |                 | Frequency Stability Grade A                                                           | −50  | —   | +50   | ppm  |
| Startup Time                                                                                                                                                                                | T <sub>SU</sub> | Minimum V <sub>DD</sub> until output frequency (F <sub>O</sub> ) within specification | —    | —   | 10    | ms   |
| Disable Time                                                                                                                                                                                | T <sub>D</sub>  | F <sub>O</sub> ≥ 10 MHz                                                               | —    | —   | 5     | μs   |
|                                                                                                                                                                                             |                 | F <sub>O</sub> < 10 MHz                                                               | —    | —   | 40    | μs   |
| Enable Time                                                                                                                                                                                 | T <sub>E</sub>  | F <sub>O</sub> ≥ 10 MHz                                                               | —    | —   | 20    | μs   |
|                                                                                                                                                                                             |                 | F <sub>O</sub> < 10 MHz                                                               | —    | —   | 60    | μs   |
| <b>*Note:</b> Total stability includes initial accuracy, operating temperature, supply voltage change, load change, shock and vibration (not under operation), and 10 years aging at 40 °C. |                 |                                                                                       |      |     |       |      |

**Table 3. Output Clock Levels and Symmetry**

$V_{DD} = 1.8 \text{ V} \pm 5\%$ , 2.5 or 3.3 V  $\pm 10\%$ ,  $T_A = -40$  to  $+85^\circ\text{C}$

| Parameter                                           | Symbol    | Test Condition                                          | Min                  | Typ                      | Max                  | Unit       |
|-----------------------------------------------------|-----------|---------------------------------------------------------|----------------------|--------------------------|----------------------|------------|
| CMOS Output Logic High                              | $V_{OH}$  |                                                         | $0.85 \times V_{DD}$ | —                        | —                    | V          |
| CMOS Output Logic Low                               | $V_{OL}$  |                                                         | —                    | —                        | $0.15 \times V_{DD}$ | V          |
| CMOS Output Logic High Drive                        | $I_{OH}$  | 3.3 V                                                   | –8                   | —                        | —                    | mA         |
|                                                     |           | 2.5 V                                                   | –6                   | —                        | —                    | mA         |
|                                                     |           | 1.8 V                                                   | –4                   | —                        | —                    | mA         |
| CMOS Output Logic Low Drive                         | $I_{OL}$  | 3.3 V                                                   | 8                    | —                        | —                    | mA         |
|                                                     |           | 2.5 V                                                   | 6                    | —                        | —                    | mA         |
|                                                     |           | 1.8 V                                                   | 4                    | —                        | —                    | mA         |
| CMOS Output Rise/Fall Time<br>(20 to 80% $V_{DD}$ ) | $T_R/T_F$ | 0.1 to 212.5 MHz,<br>$C_L = 15 \text{ pF}$              | 0.45                 | 0.8                      | 1.2                  | ns         |
|                                                     |           | 0.1 to 212.5 MHz,<br>$C_L = \text{no load}$             | 0.3                  | 0.6                      | 0.9                  | ns         |
| LVPECL Output Rise/Fall Time<br>(20 to 80% VDD)     | $T_R/T_F$ |                                                         | 100                  | —                        | 565                  | ps         |
| HCSL Output Rise/Fall Time (20 to 80% VDD)          | $T_R/T_F$ |                                                         | 100                  | —                        | 470                  | ps         |
| LVDS Output Rise/Fall Time (20 to 80% VDD)          | $T_R/T_F$ |                                                         | 350                  | —                        | 800                  | ps         |
| LVPECL Output Common Mode                           | $V_{OC}$  | $50 \Omega$ to $V_{DD} - 2 \text{ V}$ ,<br>single-ended | —                    | $V_{DD} - 1.4 \text{ V}$ | —                    | V          |
| LVPECL Output Swing                                 | $V_O$     | $50 \Omega$ to $V_{DD} - 2 \text{ V}$ ,<br>single-ended | 0.55                 | 0.8                      | 0.90                 | $V_{PPSE}$ |
| LVDS Output Common Mode                             | $V_{OC}$  | 100 $\Omega$ line-line<br>$V_{DD} = 3.3/2.5 \text{ V}$  | 1.13                 | 1.23                     | 1.33                 | V          |
|                                                     |           | 100 $\Omega$ line-line, $V_{DD} = 1.8 \text{ V}$        | 0.83                 | 0.92                     | 1.00                 | V          |
| LVDS Output Swing                                   | $V_O$     | Single-ended, 100 $\Omega$ differential<br>termination  | 0.25                 | 0.35                     | 0.45                 | $V_{PPSE}$ |
| HCSL Output Common Mode                             | $V_{OC}$  | $50 \Omega$ to ground                                   | 0.35                 | 0.38                     | 0.42                 | V          |
| HCSL Output Swing                                   | $V_O$     | Single-ended                                            | 0.58                 | 0.73                     | 0.85                 | $V_{PPSE}$ |
| Duty Cycle                                          | DC        | All formats                                             | 48                   | 50                       | 52                   | %          |

**Table 4. Output Clock Jitter and Phase Noise (LVPECL)** $V_{DD} = 2.5$  or  $3.3\text{ V} \pm 10\%$ ,  $T_A = -40$  to  $+85\text{ }^\circ\text{C}$ ; Output Format = LVPECL

| Parameter                                                           | Symbol   | Test Condition                                                     | Min | Typ  | Max | Unit   |
|---------------------------------------------------------------------|----------|--------------------------------------------------------------------|-----|------|-----|--------|
| Period Jitter (RMS)                                                 | JPRMS    | 10k samples <sup>1</sup>                                           | —   | —    | 1.3 | ps     |
| Period Jitter (Pk-Pk)                                               | JPPKPK   | 10k samples <sup>1</sup>                                           | —   | —    | 11  | ps     |
| Phase Jitter (RMS)                                                  | $\phi J$ | 1.875 MHz to 20 MHz integration bandwidth <sup>2</sup> (brickwall) | —   | 0.31 | 0.5 | ps     |
|                                                                     |          | 12 kHz to 20 MHz integration bandwidth <sup>2</sup> (brickwall)    | —   | 0.8  | 1.0 | ps     |
| Phase Noise, 156.25 MHz                                             | $\phi N$ | 100 Hz                                                             | —   | -86  | —   | dBc/Hz |
|                                                                     |          | 1 kHz                                                              | —   | -109 | —   | dBc/Hz |
|                                                                     |          | 10 kHz                                                             | —   | -116 | —   | dBc/Hz |
|                                                                     |          | 100 kHz                                                            | —   | -123 | —   | dBc/Hz |
|                                                                     |          | 1 MHz                                                              | —   | -136 | —   | dBc/Hz |
| Additive RMS Jitter Due to External Power Supply Noise <sup>3</sup> | JPSR     | 10 kHz sinusoidal noise                                            | —   | 3.0  | —   | ps     |
|                                                                     |          | 100 kHz sinusoidal noise                                           | —   | 3.5  | —   | ps     |
|                                                                     |          | 500 kHz sinusoidal noise                                           | —   | 3.5  | —   | ps     |
|                                                                     |          | 1 MHz sinusoidal noise                                             | —   | 3.5  | —   | ps     |
| Spurious                                                            | SPR      | LVPECL output, 156.25 MHz, offset > 10 kHz                         | —   | -75  | —   | dBc    |

**Notes:**

1. Applies to output frequencies: 74.17582, 74.25, 75, 77.76, 100, 106.25, 125, 148.35165, 148.5, 150, 155.52, 156.25, 212.5, 250 MHz.
2. Applies to output frequencies: 100, 106.25, 125, 148.35165, 148.5, 150, 155.52, 156.25, 212.5 and 250 MHz.
3. 156.25 MHz. Increase in jitter on output clock due to sinewave noise added to VDD ( $2.5/3.3\text{ V} = 100\text{ mVPP}$ ).

**Table 5. Output Clock Jitter and Phase Noise (LVDS)**

$V_{DD} = 1.8\text{ V} \pm 5\%$ , 2.5 or 3.3 V  $\pm 10\%$ ,  $T_A = -40$  to  $+85\text{ }^{\circ}\text{C}$ ; Output Format = LVDS

| Parameter                                                                                                                                                                                                                                                                | Symbol   | Test Condition                                                     | Min | Typ  | Max  | Unit   |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|--------------------------------------------------------------------|-----|------|------|--------|
| Period Jitter (RMS)                                                                                                                                                                                                                                                      | JPRMS    | 10k samples <sup>1</sup>                                           | —   | —    | 2.1  | ps     |
| Period Jitter (Pk-Pk)                                                                                                                                                                                                                                                    | JPPKPK   | 10k samples <sup>1</sup>                                           | —   | —    | 18   | ps     |
| Phase Jitter (RMS)                                                                                                                                                                                                                                                       | $\phi J$ | 1.875 MHz to 20 MHz integration bandwidth <sup>2</sup> (brickwall) | —   | 0.25 | 0.55 | ps     |
|                                                                                                                                                                                                                                                                          |          | 12 kHz to 20 MHz integration bandwidth <sup>2</sup> (brickwall)    | —   | 0.8  | 1.0  | ps     |
| Phase Noise, 156.25 MHz                                                                                                                                                                                                                                                  | $\phi N$ | 100 Hz                                                             | —   | –86  | —    | dBc/Hz |
|                                                                                                                                                                                                                                                                          |          | 1 kHz                                                              | —   | –109 | —    | dBc/Hz |
|                                                                                                                                                                                                                                                                          |          | 10 kHz                                                             | —   | –116 | —    | dBc/Hz |
|                                                                                                                                                                                                                                                                          |          | 100 kHz                                                            | —   | –123 | —    | dBc/Hz |
|                                                                                                                                                                                                                                                                          |          | 1 MHz                                                              | —   | –136 | —    | dBc/Hz |
| Spurious                                                                                                                                                                                                                                                                 | SPR      | LVPECL output, 156.25 MHz, offset > 10 kHz                         | —   | –75  | —    | dBc    |
| <b>Notes:</b><br>1. Applies to output frequencies: 74.17582, 74.25, 75, 77.76, 100, 106.25, 125, 148.35165, 148.5, 150, 155.52, 156.25, 212.5, 250 MHz.<br>2. Applies to output frequencies: 100, 106.25, 125, 148.35165, 148.5, 150, 155.52, 156.25, 212.5 and 250 MHz. |          |                                                                    |     |      |      |        |

**Table 6. Output Clock Jitter and Phase Noise (HCSL)**

$V_{DD} = 1.8\text{ V} \pm 5\%$ ,  $2.5\text{ or }3.3\text{ V} \pm 10\%$ ,  $T_A = -40\text{ to }+85\text{ }^{\circ}\text{C}$ ; Output Format = HCSL

| Parameter                                         | Symbol   | Test Condition                                         | Min | Typ  | Max  | Unit   |
|---------------------------------------------------|----------|--------------------------------------------------------|-----|------|------|--------|
| Period Jitter (RMS)                               | JPRMS    | 10k samples*                                           | —   | —    | 1.2  | ps     |
| Period Jitter (Pk-Pk)                             | JPPKPK   | 10k samples*                                           | —   | —    | 11   | ps     |
| Phase Jitter (RMS)                                | $\phi J$ | 1.875 MHz to 20 MHz integration bandwidth* (brickwall) | —   | 0.25 | 0.30 | ps     |
|                                                   |          | 12 kHz to 20 MHz integration bandwidth* (brickwall)    | —   | 0.8  | 1.0  | ps     |
| Phase Noise, 156.25 MHz                           | $\phi N$ | 100 Hz                                                 | —   | -90  | —    | dBc/Hz |
|                                                   |          | 1 kHz                                                  | —   | -112 | —    | dBc/Hz |
|                                                   |          | 10 kHz                                                 | —   | -120 | —    | dBc/Hz |
|                                                   |          | 100 kHz                                                | —   | -127 | —    | dBc/Hz |
|                                                   |          | 1 MHz                                                  | —   | -140 | —    | dBc/Hz |
| Spurious                                          | SPR      | LVPECL output, 156.25 MHz, offset > 10 kHz             | —   | -75  | —    | dBc    |
| *Note: Applies to an output frequency of 100 MHz. |          |                                                        |     |      |      |        |

**Table 7. Output Clock Jitter and Phase Noise (CMOS, Dual CMOS (Complementary))**

$V_{DD} = 1.8\text{ V} \pm 5\%$ , 2.5 or 3.3 V  $\pm 10\%$ ,  $T_A = -40$  to  $+85\text{ }^{\circ}\text{C}$ ; Output Format = CMOS, Dual CMOS (Complementary)

| Parameter                                                                                                                                                                                                                                                   | Symbol   | Test Condition                                                     | Min | Typ  | Max  | Unit   |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|--------------------------------------------------------------------|-----|------|------|--------|
| Phase Jitter (RMS)                                                                                                                                                                                                                                          | $\phi_J$ | 1.875 MHz to 20 MHz integration bandwidth <sup>2</sup> (brickwall) | —   | 0.25 | 0.35 | ps     |
|                                                                                                                                                                                                                                                             |          | 12 kHz to 20 MHz integration bandwidth <sup>2</sup> (brickwall)    | —   | 0.8  | 1.0  | ps     |
| Phase Noise, 156.25 MHz                                                                                                                                                                                                                                     | $\phi_N$ | 100 Hz                                                             | —   | −86  | —    | dBc/Hz |
|                                                                                                                                                                                                                                                             |          | 1 kHz                                                              | —   | −108 | —    | dBc/Hz |
|                                                                                                                                                                                                                                                             |          | 10 kHz                                                             | —   | −115 | —    | dBc/Hz |
|                                                                                                                                                                                                                                                             |          | 100 kHz                                                            | —   | −123 | —    | dBc/Hz |
|                                                                                                                                                                                                                                                             |          | 1 MHz                                                              | —   | −136 | —    | dBc/Hz |
| Spurious                                                                                                                                                                                                                                                    | SPR      | LVPECL output, 156.25 MHz, offset > 10 kHz                         | —   | −75  | —    | dBc    |
| <b>Notes:</b><br>1. Applies to output frequencies: 74.17582, 74.25, 75, 77.76, 100, 106.25, 125, 148.35165, 148.5, 150, 155.52, 156.25, 212.5 MHz.<br>2. Applies to output frequencies: 100, 106.25, 125, 148.35165, 148.5, 150, 155.52, 156.25, 212.5 MHz. |          |                                                                    |     |      |      |        |

**Table 8. Environmental Compliance and Package Information**

| Parameter                  | Conditions/Test Method   |
|----------------------------|--------------------------|
| Mechanical Shock           | MIL-STD-883, Method 2002 |
| Mechanical Vibration       | MIL-STD-883, Method 2007 |
| Solderability              | MIL-STD-883, Method 2003 |
| Gross and Fine Leak        | MIL-STD-883, Method 1014 |
| Resistance to Solder Heat  | MIL-STD-883, Method 2036 |
| Moisture Sensitivity Level | MSL 1                    |
| Contact Pads               | Gold over Nickel         |

Table 9. Thermal Characteristics

| Parameter                              | Symbol        | Test Condition | Value | Unit |
|----------------------------------------|---------------|----------------|-------|------|
| Thermal Resistance Junction to Ambient | $\theta_{JA}$ | Still air      | 110   | °C/W |

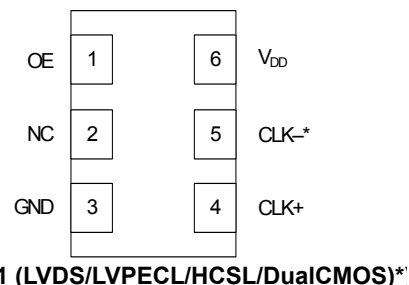
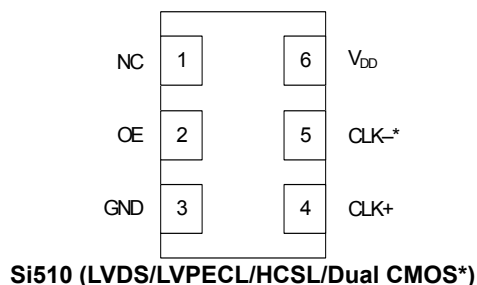
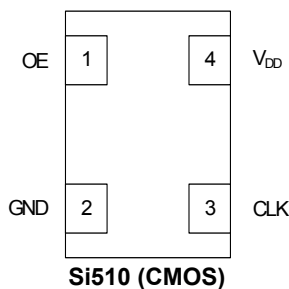
Table 10. Absolute Maximum Ratings<sup>1</sup>

| Parameter                                                               | Symbol     | Rating                 | Unit |
|-------------------------------------------------------------------------|------------|------------------------|------|
| Maximum Operating Temperature                                           | $T_{AMAX}$ | 85                     | °C   |
| Storage Temperature                                                     | $T_S$      | –55 to +125            | °C   |
| Supply Voltage                                                          | $V_{DD}$   | –0.5 to +3.8           | V    |
| Input Voltage (any input pin)                                           | $V_I$      | –0.5 to $V_{DD} + 0.3$ | V    |
| ESD Sensitivity (HBM, per JESD22-A114)                                  | HBM        | 2                      | kV   |
| Soldering Temperature (Pb-free profile) <sup>2</sup>                    | $T_{PEAK}$ | 260                    | °C   |
| Soldering Temperature Time at $T_{PEAK}$ (Pb-free profile) <sup>2</sup> | $T_P$      | 20–40                  | sec  |

**Notes:**

1. Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation or specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.
2. The device is compliant with JEDEC J-STD-020.

## 2. Pin Descriptions



\*Supports integrated 1:2 CMOS buffer. See ordering information and section 2.1 “Dual CMOS Buffer”.

**Table 11. Si510 Pin Descriptions (CMOS)**

| Pin | Name            | CMOS Function                                                                                                                         |
|-----|-----------------|---------------------------------------------------------------------------------------------------------------------------------------|
| 1   | OE              | Output Enable. Includes internal pull-up for OE active high. Includes internal pull-down for OE active low. See ordering information. |
| 2   | GND             | Electrical and Case Ground.                                                                                                           |
| 3   | CLK             | Clock Output.                                                                                                                         |
| 4   | V <sub>DD</sub> | Power Supply Voltage.                                                                                                                 |

**Table 12. Si510 Pin Descriptions (LVPECL/LVDS/HCSL, Dual CMOS, OE Pin 2)**

| Pin | Name            | LVPECL/LVDS/HCSL Function                                                                                                             |
|-----|-----------------|---------------------------------------------------------------------------------------------------------------------------------------|
| 1   | NC              | No connect. Make no external connection to this pin.                                                                                  |
| 2   | OE              | Output Enable. Includes internal pull-up for OE active high. Includes internal pull-down for OE active low. See ordering information. |
| 3   | GND             | Electrical and Case Ground.                                                                                                           |
| 4   | CLK+            | Clock Output.                                                                                                                         |
| 5   | CLK–            | Complementary Clock Output.                                                                                                           |
| 6   | V <sub>DD</sub> | Power Supply Voltage.                                                                                                                 |

**Table 13. Si511 Pin Descriptions (LVPECL/LVDS/HCSL, Dual CMOS, OE Pin 1)**

| Pin | Name            | LVPECL/LVDS/HCSL Function                                                                                                             |
|-----|-----------------|---------------------------------------------------------------------------------------------------------------------------------------|
| 1   | OE              | Output Enable. Includes internal pull-up for OE active high. Includes internal pull-down for OE active low. See ordering information. |
| 2   | NC              | No connect. Make no external connection to this pin.                                                                                  |
| 3   | GND             | Electrical and Case Ground.                                                                                                           |
| 4   | CLK+            | Clock Output.                                                                                                                         |
| 5   | CLK–            | Complementary Clock Output.                                                                                                           |
| 6   | V <sub>DD</sub> | Power Supply Voltage.                                                                                                                 |

## 2.1. Dual CMOS Buffer

Dual CMOS output format ordering options support either complementary or in-phase output signals. This feature enables replacement of multiple XOs with a single Si510/11 device.

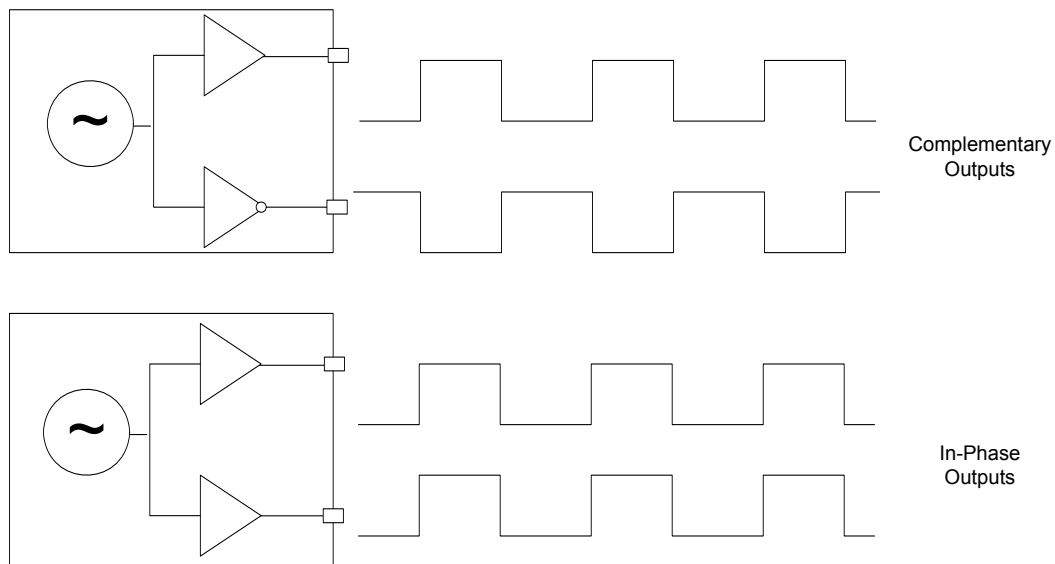


**Figure 1. Integrated 1:2 CMOS Buffer Supports Complementary or In-Phase Outputs**

## 3. Ordering Information

The Si510/511 supports a wide variety of options including frequency, stability, output format, and  $V_{DD}$ . Specific device configurations are programmed into the Si510/511 at time of shipment. Configurations can be specified using the Part Number Configuration chart below. Silicon Labs provides a web browser-based part number configuration utility to simplify this process. Refer to [www.silabs.com/VCXOpartnumber](http://www.silabs.com/VCXOpartnumber) to access this tool. The Si510/511 XO series is supplied in industry-standard, RoHS compliant, lead-free, 3.2 x 5.0 mm and 5 x 7 mm packages. Tape and reel packaging is an ordering option.

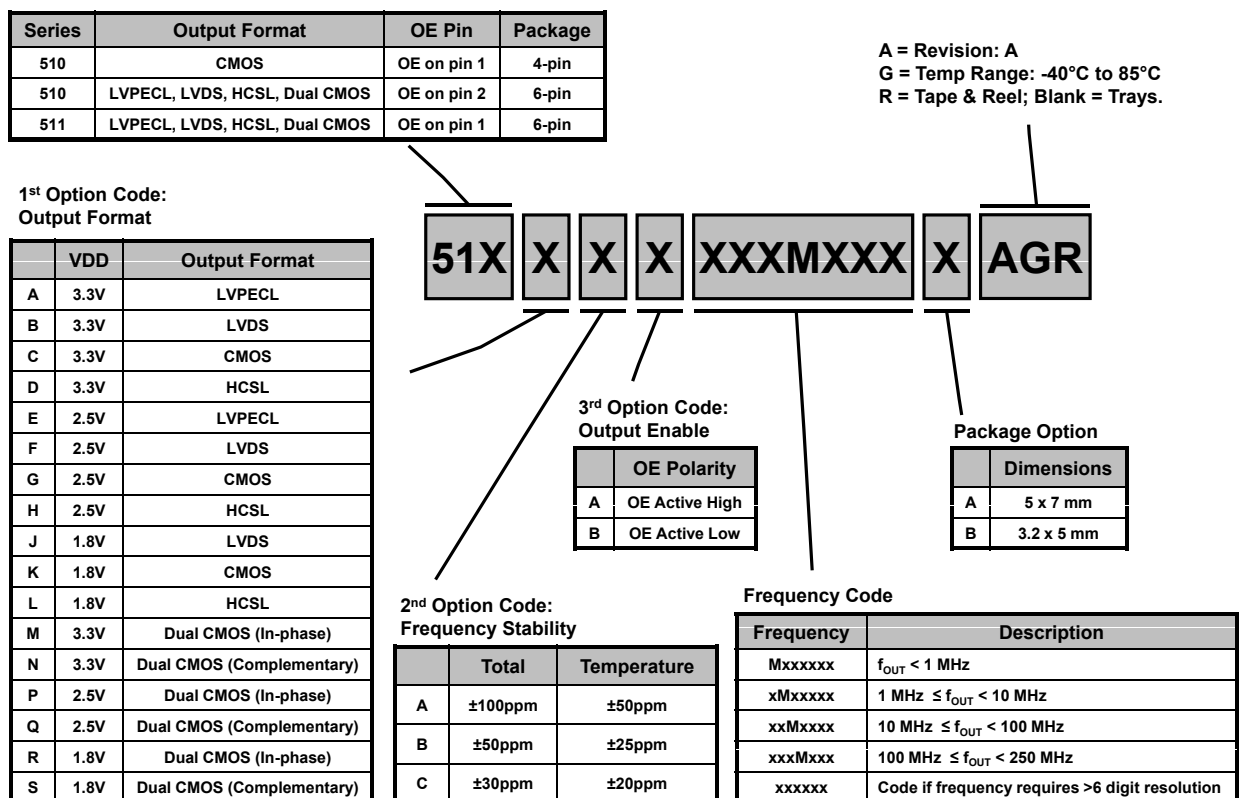


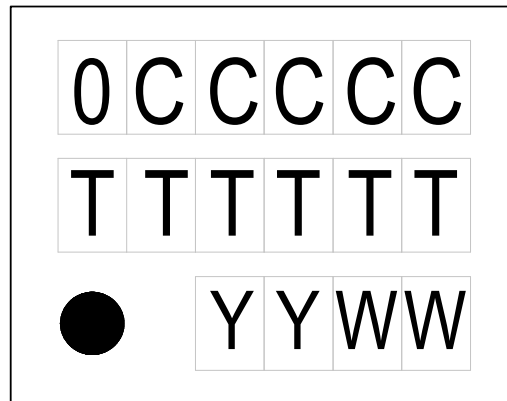
Figure 2. Part Number Syntax

Example orderable part number: 510ECB156M250AAG supports 2.5 V LVPECL, ±30 ppm total stability, OE active low in 5 x 7 mm package across -40°C to 85°C temperature range. The output frequency is 156.25 MHz.

**Note:** CMOS and Dual CMOS maximum frequency is 212.5 MHz.

## 4. Si510/511 Mark Specification

Figure 3 illustrates the mark specification for the Si510/511. Use the part number configuration utility located at: [www.silabs.com/VCXOpartnumber](http://www.silabs.com/VCXOpartnumber) to cross-reference the mark code to a specific device configuration.



0 = Si510, 1 = Si511  
CCCCC = mark code  
TTTTTT = assembly manufacturing code  
YY = year  
WW = work week

**Figure 3. Top Mark**

## 5. Package Outline Diagram: 5 x 7 mm, 4-pin

Figure 4 illustrates the package details for the 5 x 7 mm Si510/511. Table 14 lists the values for the dimensions shown in the illustration.

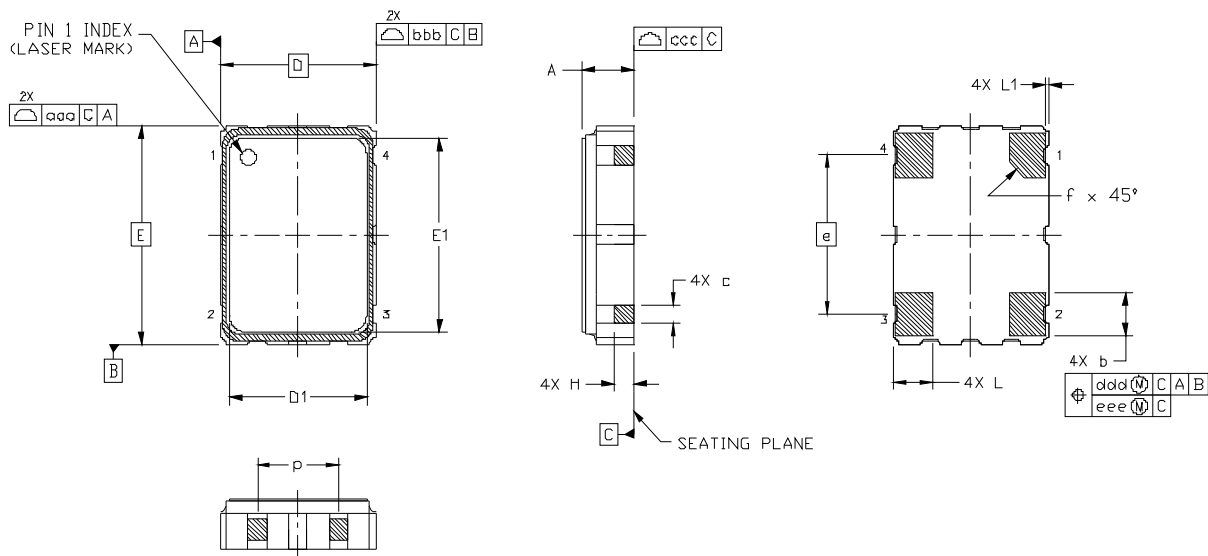


**Figure 4. Si510/511 Outline Diagram**

**Table 14. Package Diagram Dimensions (mm)**

| Dimension                                                               | Min      | Nom  | Max  |
|-------------------------------------------------------------------------|----------|------|------|
| A                                                                       | 1.50     | 1.65 | 1.80 |
| b                                                                       | 1.30     | 1.40 | 1.50 |
| c                                                                       | 0.50     | 0.60 | 0.70 |
| D                                                                       | 5.00 BSC |      |      |
| D1                                                                      | 4.30     | 4.40 | 4.50 |
| e                                                                       | 5.08 BSC |      |      |
| f                                                                       | 0.50 TYP |      |      |
| E                                                                       | 7.00 BSC |      |      |
| E1                                                                      | 6.10     | 6.20 | 6.30 |
| H                                                                       | 0.55     | 0.65 | 0.75 |
| L                                                                       | 1.17     | 1.27 | 1.37 |
| L1                                                                      | 0.05     | 0.10 | 0.15 |
| p                                                                       | 2.50     | 2.60 | 2.70 |
| aaa                                                                     | 0.15     |      |      |
| bbb                                                                     | 0.15     |      |      |
| ccc                                                                     | 0.10     |      |      |
| ddd                                                                     | 0.10     |      |      |
| eee                                                                     | 0.05     |      |      |
| <b>Notes:</b>                                                           |          |      |      |
| 1. All dimensions shown are in millimeters (mm) unless otherwise noted. |          |      |      |
| 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.                   |          |      |      |

## 6. PCB Land Pattern: 5 x 7 mm, 4-pin

Figure 5 illustrates the 5 x 7 mm PCB land pattern for the 5 x 7 mm Si510/511. Table 15 lists the values for the dimensions shown in the illustration.

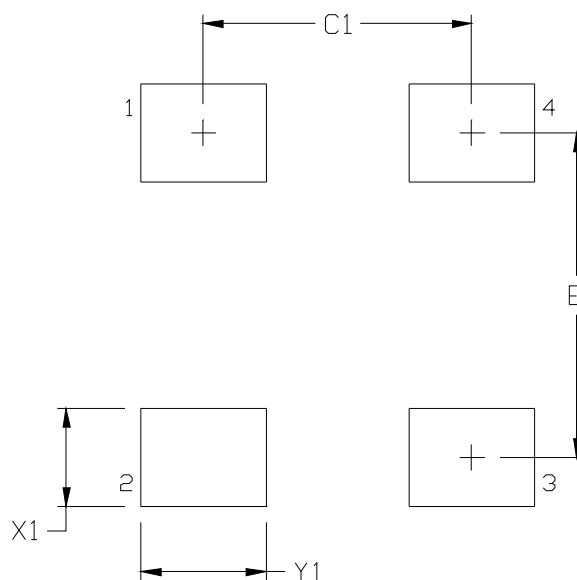


**Figure 5. Si510/511 PCB Land Pattern**

**Table 15. PCB Land Pattern Dimensions (mm)**

| Dimension | (mm) |
|-----------|------|
| C1        | 4.20 |
| E         | 5.08 |
| X1        | 1.55 |
| Y1        | 1.95 |

**Notes:**

**General**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

**Solder Mask Design**

5. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

**Stencil Design**

6. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
7. The stencil thickness should be 0.125 mm (5 mils).
8. The ratio of stencil aperture to land pad size should be 1:1.

**Card Assembly**

9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020D specification for Small Body Components.

## 7. Package Outline Diagram: 5 x 7 mm, 6-pin

Figure 6 illustrates the package details for the Si510/511. Table 16 lists the values for the dimensions shown in the illustration.

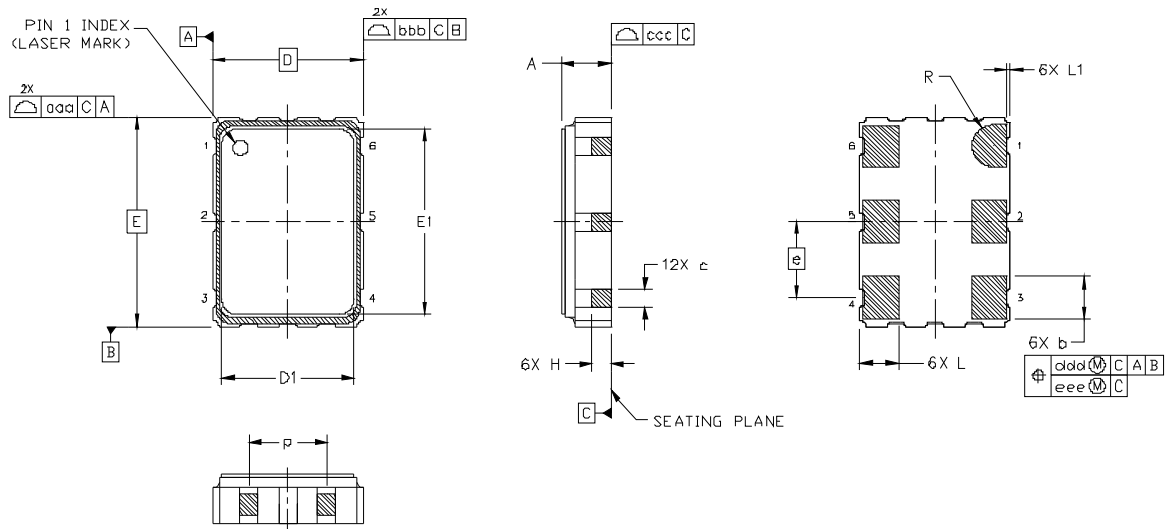


**Figure 6. Si510/511 Outline Diagram**

**Table 16. Package Diagram Dimensions (mm)**

| Dimension | Min      | Nom  | Max  |
|-----------|----------|------|------|
| A         | 1.50     | 1.65 | 1.80 |
| b         | 1.30     | 1.40 | 1.50 |
| c         | 0.50     | 0.60 | 0.70 |
| D         | 5.00 BSC |      |      |
| D1        | 4.30     | 4.40 | 4.50 |
| e         | 2.54 BSC |      |      |
| E         | 7.00 BSC |      |      |
| E1        | 6.10     | 6.20 | 6.30 |
| H         | 0.55     | 0.65 | 0.75 |
| L         | 1.17     | 1.27 | 1.37 |
| L1        | 0.05     | 0.10 | 0.15 |
| p         | 1.80     | —    | 2.60 |
| R         | 0.70 REF |      |      |
| aaa       | 0.15     |      |      |
| bbb       | 0.15     |      |      |
| ccc       | 0.10     |      |      |
| ddd       | 0.10     |      |      |
| eee       | 0.05     |      |      |

**Notes:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

## 8. PCB Land Pattern: 5 x 7 mm, 6-pin

Figure 7 illustrates the 5 x 7 mm PCB land pattern for the Si510/511. Table 17 lists the values for the dimensions shown in the illustration.

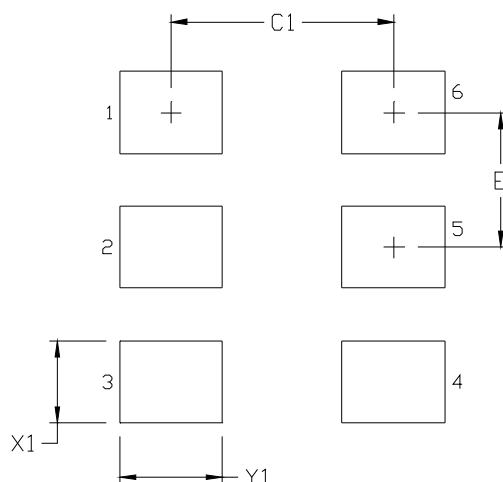


**Figure 7. Si510/511 PCB Land Pattern**

**Table 17. PCB Land Pattern Dimensions (mm)**

| Dimension | (mm) |
|-----------|------|
| C1        | 4.20 |
| E         | 2.54 |
| X1        | 1.55 |
| Y1        | 1.95 |

**Notes:**

**General**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

**Solder Mask Design**

5. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60  $\mu$ m minimum, all the way around the pad.

**Stencil Design**

6. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
7. The stencil thickness should be 0.125 mm (5 mils).
8. The ratio of stencil aperture to land pad size should be 1:1.

**Card Assembly**

9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

## 9. Package Outline Diagram: 3.2 x 5 mm, 4-pin

Figure 8 illustrates the package details for the 3.2 x 5 mm Si510/511. Table 18 lists the values for the dimensions shown in the illustration.

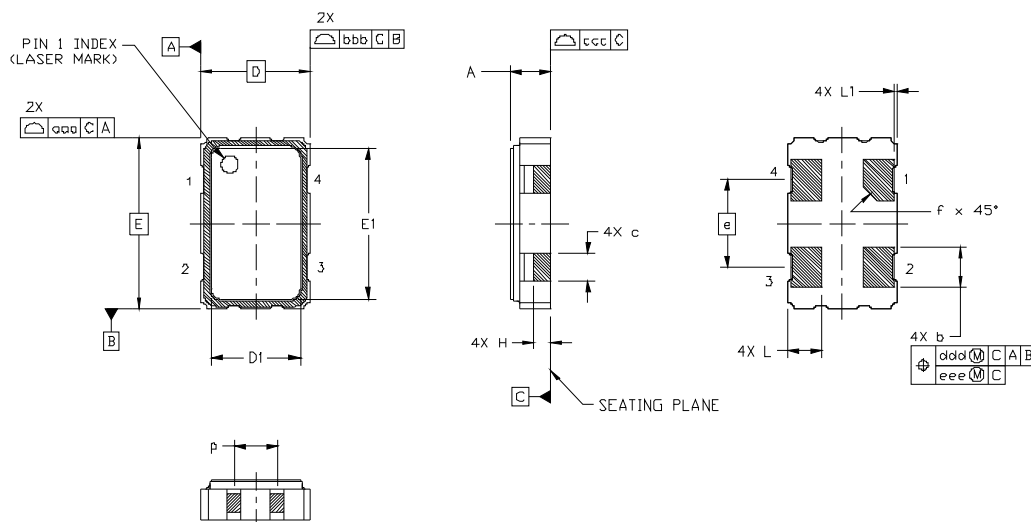


**Figure 8. Si510/511 Outline Diagram**

**Table 18. Package Diagram Dimensions (mm)**

| Dimension                                                               | Min      | Nom  | Max  |
|-------------------------------------------------------------------------|----------|------|------|
| A                                                                       | 1.06     | 1.17 | 1.28 |
| b                                                                       | 1.10     | 1.20 | 1.30 |
| c                                                                       | 0.70     | 0.80 | 0.90 |
| D                                                                       | 3.20 BSC |      |      |
| D1                                                                      | 2.55     | 2.60 | 2.65 |
| e                                                                       | 2.54 BSC |      |      |
| f                                                                       | 0.40 TYP |      |      |
| E                                                                       | 5.00 BSC |      |      |
| E1                                                                      | 4.35     | 4.40 | 4.45 |
| H                                                                       | 0.40     | 0.50 | 0.60 |
| L                                                                       | 0.90     | 1.00 | 1.10 |
| L1                                                                      | 0.05     | 0.10 | 0.15 |
| p                                                                       | 1.17     | 1.27 | 1.37 |
| aaa                                                                     | 0.15     |      |      |
| bbb                                                                     | 0.15     |      |      |
| ccc                                                                     | 0.10     |      |      |
| ddd                                                                     | 0.10     |      |      |
| eee                                                                     | 0.05     |      |      |
| <b>Notes:</b>                                                           |          |      |      |
| 1. All dimensions shown are in millimeters (mm) unless otherwise noted. |          |      |      |
| 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.                   |          |      |      |

## 10. PCB Land Pattern: 3.2 x 5 mm, 4-pin

Figure 9 illustrates the 3.2 x 5 mm PCB land pattern for the Si510/511. Table 19 lists the values for the dimensions shown in the illustration.

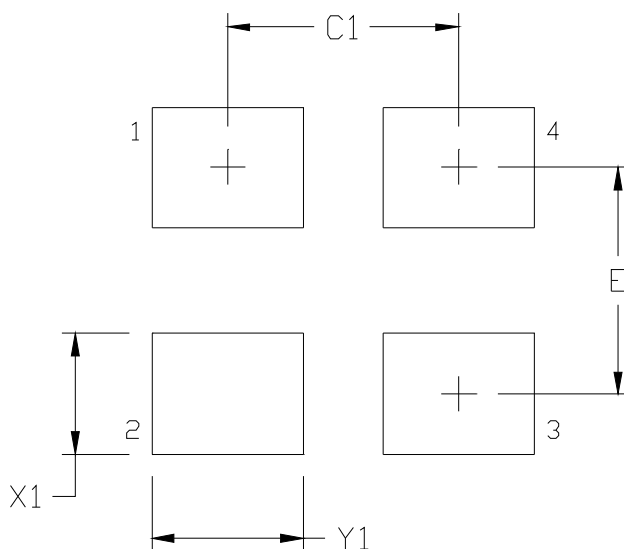


**Figure 9. Si510/511 PCB Land Pattern**

**Table 19. PCB Land Pattern Dimensions (mm)**

| Dimension | (mm) |
|-----------|------|
| C1        | 2.60 |
| E         | 2.54 |
| X1        | 1.35 |
| Y1        | 1.70 |

**Notes:**

**General**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

**Solder Mask Design**

5. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

**Stencil Design**

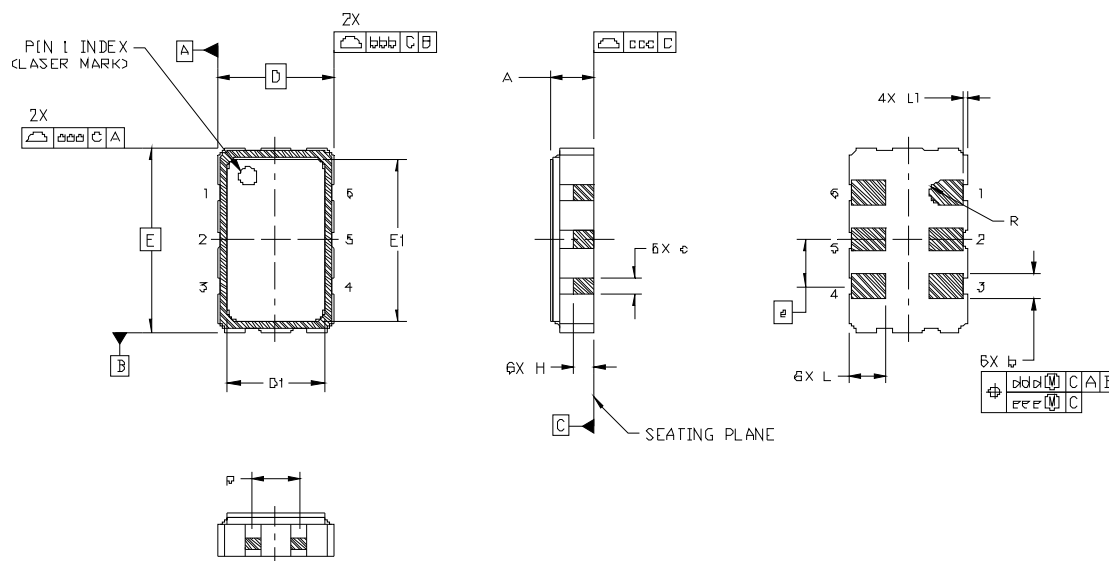
6. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
7. The stencil thickness should be 0.125 mm (5 mils).
8. The ratio of stencil aperture to land pad size should be 1:1.

**Card Assembly**

9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

## 11. Package Outline Diagram: 3.2 x 5 mm, 6-Pin

Figure 10 illustrates the package details for the 3.2 x 5 mm Si510/511. Table 20 lists the values for the dimensions shown in the illustration.



### Figure 10. Si510/511 Outline Diagram

**Table 20. Package Diagram Dimensions (mm)**

| Dimension | Min      | Nom  | Max  |
|-----------|----------|------|------|
| A         | 1.06     | 1.17 | 1.28 |
| b         | 0.54     | 0.64 | 0.74 |
| c         | 0.35     | 0.45 | 0.55 |
| D         | 3.20 BSC |      |      |
| D1        | 2.55     | 2.60 | 2.65 |
| e         | 1.27 BSC |      |      |
| E         | 5.00 BSC |      |      |
| E1        | 4.35     | 4.40 | 4.45 |
| H         | 0.45     | 0.55 | 0.65 |
| L         | 0.90     | 1.00 | 1.10 |
| L1        | 0.05     | 0.10 | 0.15 |
| p         | 1.17     | 1.27 | 1.37 |
| R         | 0.32 REF |      |      |
| aaa       | 0.15     |      |      |
| bbb       | 0.15     |      |      |
| ccc       | 0.10     |      |      |
| ddd       | 0.10     |      |      |
| eee       | 0.05     |      |      |

**Notes:**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

## 12. PCB Land Pattern: 3.2 x 5.0 mm, 6-pin

Figure 11 illustrates the 3.2 x 5.0 mm PCB land pattern for the Si510/511. Table 21 lists the values for the dimensions shown in the illustration.

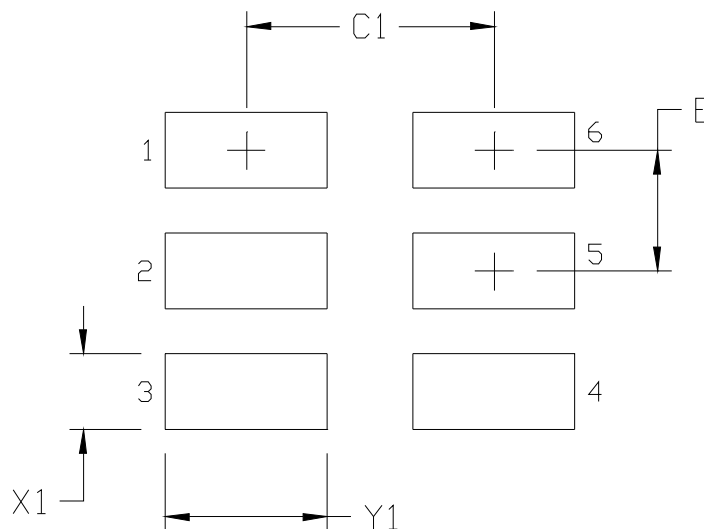


**Figure 11. Si510/511 Recommended PCB Land Pattern**

**Table 21. PCB Land Pattern Dimensions (mm)**

| Dimension | (mm) |
|-----------|------|
| C1        | 2.60 |
| E         | 1.27 |
| X1        | 0.80 |
| Y1        | 1.70 |

**Notes:**

**General**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
3. This Land Pattern Design is based on the IPC-7351 guidelines.
4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

**Solder Mask Design**

5. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60  $\mu$ m minimum, all the way around the pad.

**Stencil Design**

6. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
7. The stencil thickness should be 0.125 mm (5 mils).
8. The ratio of stencil aperture to land pad size should be 1:1.

**Card Assembly**

9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

## DOCUMENT CHANGE LIST

### Revision 0.9 to Revision 1.0

- Updated Table 1 on page 4.
  - Updates to supply current typical and maximum values for CMOS, LVDS, LVPECL and HCSL.
  - CMOS frequency test condition corrected to 100 MHz.
  - Updates to OE VIH minimum and VIL maximum values.
- Updated Table 2 on page 5.
  - Dual CMOS nominal frequency maximum added.
  - Total stability footnotes clarified for 10 year aging at 40 °C.
  - Disable time maximum values updated.
  - Enable time parameter added.
- Updated Table 3 on page 6.
  - CMOS output rise / fall time typical and maximum values updated.
  - LVPECL/HCSL output rise / fall time maximum value updated.
  - LVPECL output swing maximum value updated.
  - LVDS output common mode typical and maximum values updated.
  - HCSL output swing maximum value updated.
  - Duty cycle minimum and maximum values tightened to 48/52%.
- Updated Table 4 on page 7.
  - Phase jitter test condition and maximum value updated.
  - Phase noise typical values updated.
  - Additive RMS jitter due to external power supply noise typical values updated.
  - Footnote 3 updated limiting the VDD to 2.5/3.3V
- Added Tables 5, 6, 7 for LVDS, HCSL, CMOS, and Dual CMOS operations.
- Moved Absolute Maximum Ratings table.
- Added note to Figure 2 clarifying CMOS and Dual CMOS maximum frequency.
- Updated Figure 10 outline diagram to correct pinout.

### Revision 1.0 to Revision 1.1

- Updated Table 3.
  - CMOS Output Rise/Fall Time Test Condition updated.

### Revision 1.1 to Revision 1.2

- Updated Table 3.
  - Separated LVPECL and HCSL output Rise/Fall time specs.
  - Min Rise/Fall times added.

**NOTES:**

## CONTACT INFORMATION

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